2SC4425



# 400V/25A Switching Regulator Applications

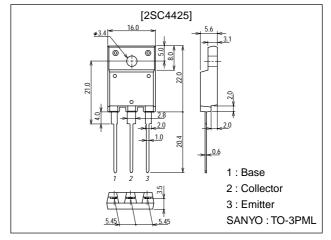
#### **Features**

- · High breakdown voltage, high reliability.
- · Fast switching speed ( $t_f$ : 0.1 $\mu$ s typ).
- · Wide ASO.
- · Adoption of MBIT process.
- · Micaless package facilitating easy mounting.

## **Package Dimensions**

unit:mm

2039D



# **Specifications**

### Absolute Maximum Ratings at Ta = 25°C

| Parameter                    | Symbol           | Conditions               | Ratings     | Unit |
|------------------------------|------------------|--------------------------|-------------|------|
| Collector-to-Base Voltage    | V <sub>CBO</sub> |                          | 500         | V    |
| Collector-to-Emitter Voltage | V <sub>CEO</sub> |                          | 400         | V    |
| Emitter-to-Base Voltage      | V <sub>EBO</sub> |                          | 7           | V    |
| Collector Current            | IC               |                          | 25          | Α    |
| Collector Current (Pulse)    | I <sub>CP</sub>  | PW≤300μs, duty cycle≤10% | 40          | А    |
| Base Current                 | I <sub>B</sub>   |                          | 8           | А    |
| Collector Dissipation        | PC               |                          | 3           | W    |
|                              |                  | Tc=25°C                  | 65          | W    |
| Junction Temperature         | Tj               |                          | 150         | °C   |
| Storage Temperature          | Tstg             |                          | -55 to +150 | °C   |

#### Electrical Characteristics at Ta = 25°C

| Parameter                | Symbol             | Conditions                                | Ratings |     |     | Unit |
|--------------------------|--------------------|---|---------|-----|-----|------|
|                          |                    |   | min     | typ | max |      |
| Collector Cutoff Current | ICBO               | V <sub>CB</sub> =400V, I <sub>E</sub> =0  |         |     | 10  | μΑ   |
| Emitter Cutoff Current   | I <sub>EBO</sub>   | V <sub>EB</sub> =5V, I <sub>C</sub> =0    |         |     | 10  | μΑ   |
| DC Current Gain          | h <sub>FE</sub> 1* | V <sub>CE</sub> =5V, I <sub>C</sub> =3.2A | 15      |     | 50  |      |
|                          | h <sub>FE</sub> 2  | V <sub>CE</sub> =5V, I <sub>C</sub> =16A  | 10      |     |     |      |
|                          | hFE3               | V <sub>CE</sub> =5V, I <sub>C</sub> =10mA | 10      |     |     |      |

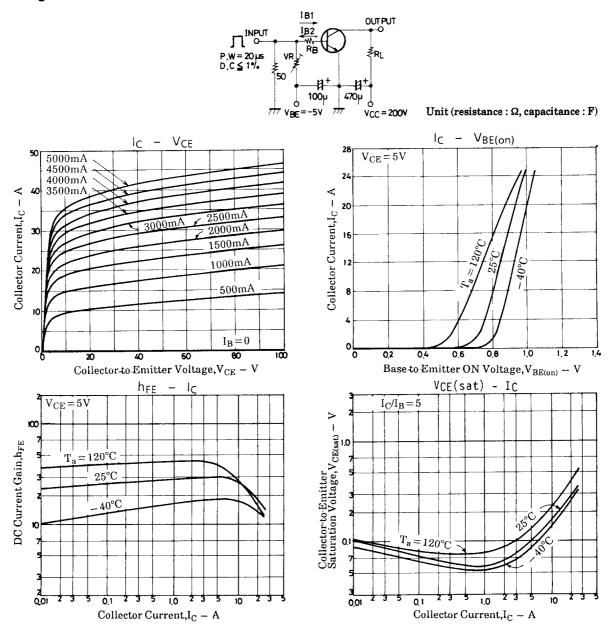
<sup>\*</sup>: The  $h_{FE}1$  of the 2SC4425 is classified as follows. When specifying the  $h_{FE}1$  rank, specify two ranks or more in principle.

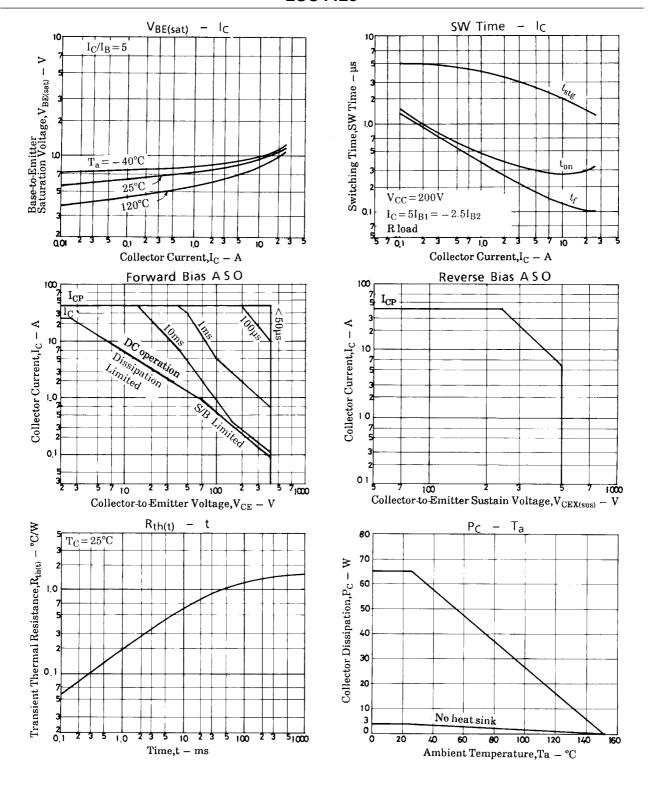
15 L 30 20 M 40 30 N 50

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| Parameter                               | Symbol                | Conditions   | Ratings |     |     | Unit  |
|---|-----------------------|--|---------|-----|-----|-------|
|   |                       |  | min     | typ | max | Offic |
| Collector-to-Emitter Saturation Voltage | VCE(sat)              | I <sub>C</sub> =16A, I <sub>B</sub> =3.2A  |         |     | 0.8 | V     |
| Base-to-Emitter Saturation Voltage      | V <sub>BE(sat)</sub>  | I <sub>C</sub> =16A, I <sub>B</sub> =3.2A  |         |     | 1.5 | V     |
| Gain-Bandwidth Product                  | f <sub>T</sub>        | V <sub>CE</sub> =10V, I <sub>C</sub> =3.2A   |         | 20  |     | MHz   |
| Output Capacitance                      | C <sub>ob</sub>       | V <sub>CB</sub> =10V, f=1MHz   |         | 300 |     | pF    |
| Collector-to-Base Breakdown Voltage     | V(BR)CBO              | I <sub>C</sub> =1mA, I <sub>E</sub> =0   | 500     |     |     | V     |
| Collector-to-Emitter Breakdown Voltage  | V(BR)CEO              | I <sub>C</sub> =10mA, R <sub>BE</sub> =∞   | 400     |     |     | V     |
| Emitter-to-Base Breakdown Voltage       | V <sub>(BR)EBO</sub>  | I <sub>E</sub> =1mA, I <sub>C</sub> =0   | 7       |     |     | V     |
| Collector-to-Emitter Sustain Voltage    | V <sub>CEX(sus)</sub> | I <sub>C</sub> =10A, I <sub>B1</sub> =1A, I <sub>B2</sub> =-4A, L=200μH, Clamped                           | 400     |     |     | V     |
| Turn-ON Time                            | ton                   | I <sub>C</sub> =20A, I <sub>B1</sub> =4A, I <sub>B2</sub> =-8A, R <sub>L</sub> =10Ω, V <sub>CC</sub> =200V |         |     | 0.5 | μs    |
| Storage Time                            | t <sub>stg</sub>      | I <sub>C</sub> =20A, I <sub>B1</sub> =4A, I <sub>B2</sub> =-8A, R <sub>L</sub> =10Ω, V <sub>CC</sub> =200V |         |     | 2.5 | μs    |
| Fall Time                               | t <sub>f</sub>        | I <sub>C</sub> =20A, I <sub>B1</sub> =4A, I <sub>B2</sub> =-8A, R <sub>L</sub> =10Ω, V <sub>CC</sub> =200V |         |     | 0.3 | μs    |

### **Switching Time Test Circuit**





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